E4MS018120QT

Automotive Silicon Carbide Power MOSFET

Features

- Industry compatible drive voltage 15 V ...18 V/-4 V ...0 V
- Low $R_{DS(on)}$ at high operating temperatures
- Improved device capacitance ratio (C_{iss}/C_{rss})
- Halogen free, RoHS compliant
- Automotive Qualified (AEC-Q101) and PPAP Capable

Benefits

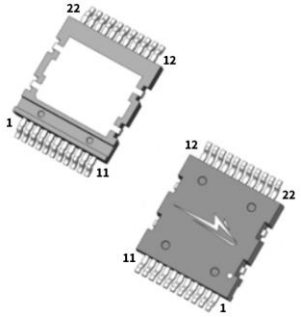
- Higher efficiency with lower switching losses and EMI
- Faster switching operation enabling high power density
- Enables system level price performance optimization
- Reduction in system level cooling requirements

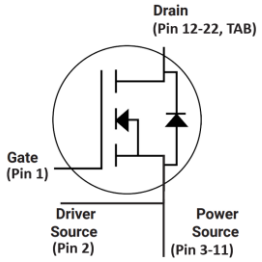
Typical Applications

- Onboard charger
- High voltage DC/DC converters
- HVAC compressors
- Battery management systems

Package

RoHS compliant





Orderable Part Number	Package Type	Marking
E4MS018120QT-TR	Q-TSC	E4MS018120QT

Absolute Maximum Ratings

Stress beyond those listed under absolute maximum ratings may damage the device.

Symbol	Parameter	Min.	Max.	Unit	Conditions	Note
$V_{DS(max)}$	Drain-Source Voltage		1200	V		
$V_{GS(max)}$	Maximum Gate – Source Voltage (Transient)	-10	+23			Note 1
I_D	DC Continuous Drain Current		119	A	V_{GS} = 18 V, T_C = 25 °C, $T_J \leq$ 175 °C	Note 2
			85		V_{GS} = 18 V, T_C = 100 °C, $T_J \leq$ 175 °C	
I_{DM}	Pulsed Drain Current		369		V_{GS} = 18 V, T_C = 25 °C, t_{Pmax} limited by T_{jmax}	
P_D	Power Dissipation		483	W	T_C = 25 °C, T_J = 175 °C	Note 3
T_J, T_{stg}	Operating Junction and Storage Temperature	-55	+175	°C		
T_L	Solder Temperature		260		According to JEDEC J-STD-020	

Note (1): Refer to AN PRD-09634
Note (2): Current limit calculated by $I_{D(max)} = \sqrt{(P_D / R_{DS(typ)}(T_{J(max)}, I_{D(max)}))}$
Note (3): $P_D = (T_J - T_C) / R_{th(JC,Max)}$

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Electrical Characteristics (T_C = 25 °C unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions	Note
$V_{(BR)DSS}$	Drain – Source Breakdown Voltage	1200			V	V_{GS} = 0 V, I_D =100 µA	
$V_{GS(th)}$	Gate Threshold Voltage	2.0	2.6	3.9	V	V_{DS} = V_{GS}, I_D = 14.5 mA	Fig. 11, Note 1
			2.0		V	V_{DS} = V_{GS}, I_D = 14.5 mA, T_J = 175 °C	
I_{DSS}	Zero Gate Voltage Drain Current		1	50	µA	V_{DS} = 1200 V, V_{GS} = 0 V	
I_{GSS}	Gate-Source Leakage Current		10	250	nA	V_{GS} = 18 V, V_{DS} = 0 V	
$V_{GS(op)}$	Recommended Turn on Gate-Source Voltage		+15…+18		V		Note 4
	Recommended Turn off Gate-Source Voltage		-4…0				
$R_{DS(on)}$	Drain-Source On-State Resistance		18	23.4	mΩ	V_{GS} = 18 V, I_D = 52.7 A	Fig. 4, 5, 6
			33.8			V_{GS} = 18 V, I_D = 52.7 A, T_J = 175 °C	
			21			V_{GS} = 15 V, I_D = 52.7 A	
g_{fs}	Transconductance		39		S	V_{DS} = 20 V, I_D = 52.7 A	Fig. 7
			38			V_{DS} = 20 V, I_D = 52.7 A, T_J = 175 °C	
$R_{DS(on)Tempco}$	On Resistance Temperature Coefficient		1.88			V_{GS} = 18 V, I_D = 52.7 A	Note 5
C_{iss}	Input Capacitance		4105		pF	V_{GS} = 0 V, V_{DS} = 1000 V f = 100 kHz V_{AC} = 25 mV	Fig. 17, 18
C_{oss}	Output Capacitance		148				
C_{rss}	Reverse Transfer Capacitance		6.5				
C_{iss}/C_{rss}	Capacitance Ratio		630				Note 6
E_{oss}	C_{OSS} Stored Energy		96		µJ		Fig. 16
$C_{o(er)}$	Effective Output Capacitance (Energy Related)		215		pF	V_{GS} = 0 V, V_{DS} = 0 V … 800 V	Note 7
$C_{o(tr)}$	Effective Output Capacitance (Time Related)		350				
E_{on}	Turn-On Switching Energy (Body Diode FWD) T_j = 25 °C T_j = 175 °C		347 343		µJ	V_{DS} = 800 V, V_{GS} = -4 V / 18 V, I_D = 52.7 A, $R_{G(ext)}$ = 2 Ω, L_σ = 14 nH	Fig. 25, 27, 29
E_{off}	Turn-Off Switching Energy (Body Diode FWD) T_j = 25 °C T_j = 175 °C		133 130				Fig. 25, 28, 29
$t_{d(on)}$	Turn-On Delay Time		14		ns	V_{DS} = 800 V, V_{GS} =-4 V / 18 V, I_D = 52.7 A, $R_{G(ext)}$ = 2 Ω, L_σ = 14 nH Timing relative to I_{DS} Inductive load	Fig. 26, 27, 29
t_r	Rise Time		5				
$t_{d(off)}$	Turn-Off Delay Time		34				Fig. 26, 28, 29
t_f	Fall Time		12				
$R_{G(int)}$	Internal Gate Resistance		1.2		Ω	f = 1 MHz	
Q_{gs}	Gate to Source Charge		47		nC	V_{DS} = 800 V, V_{GS} = -4 V/ 18 V I_D = 52.7 A	Fig. 12
Q_{gd}	Gate to Drain Charge		50				
Q_g	Total Gate Charge		172				

Note (4): Refer to AN PRD-08999.
Note (5): $R_{DS(on)Tempco}$ refers to $R_{DS(on)}$ at 175 °C / $R_{DS(on)}$ at 25 °C. This is a E4MS 1200 V product family value.
Note (6): Capacitance ratio is a FOM for partial turn-on immunity AN PRD-06933. This is a E4MS 1200 V product family value.
Note (7): $C_{o(er)}$, a lumped capacitance that gives the same stored energy as C_{oss} while V_{DS} is rising from 0 V to 800 V.
$C_{o(tr)}$, a lumped capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 V to 800 V.

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Reverse Diode Characteristics (T_C = 25 °C unless otherwise specified)

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_{SD}	Diode Forward Voltage	5.1		V	V_{GS} = -4 V, I_{SD} = 26.4 A, T_J = 25 °C	Fig. 8, 9, 10
		4.5			V_{GS} = -4 V, I_{SD} = 26.4 A, T_J = 175 °C	
I_S	Continuous Diode Forward Current		74	A	V_{GS} = -4 V, T_C = 25 °C	
I_{SM}	Diode Pulse Current		369		V_{GS} = -4 V, pulse width t_p limited by T_{jmax}	
t_{rr}	Reverse Recovery Time	17		ns	V_{GS} = -4 V, I_{SD} = 52.7 A, V_R = 800 V, T_J = 175 °C, di_f/dt = 16694 A/µs	Fig. 30
Q_{rr}	Reverse Recovery Charge	1099		nC		
I_{RRM}	Peak Reverse Recovery Current	104		A		
E_{RR}	Reverse Recovery Energy T_j = 25 °C T_j = 175 °C	 439 720		µJ	V_{DS} = 800 V, I_{DS} = 52.7 A, V_{GS} = -4 V / 18 V, $R_{G(ext)}$ = 2 Ω, L_σ = 14 nH	

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	0.24	0.31	°C/W		

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Typical Performance

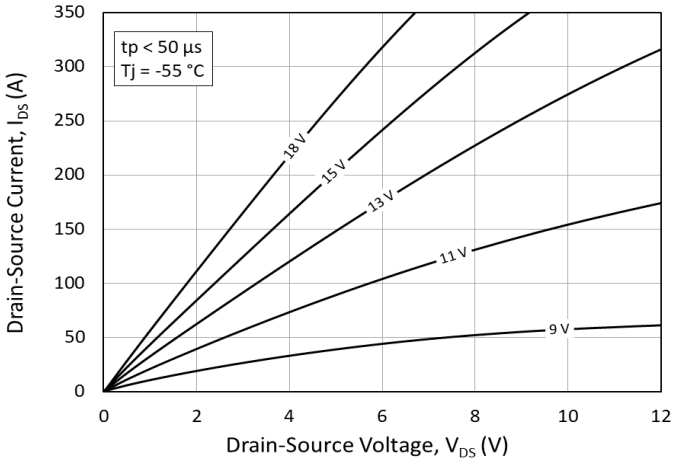

Figure 1. Output Characteristics T_{VJ} = -55 °C

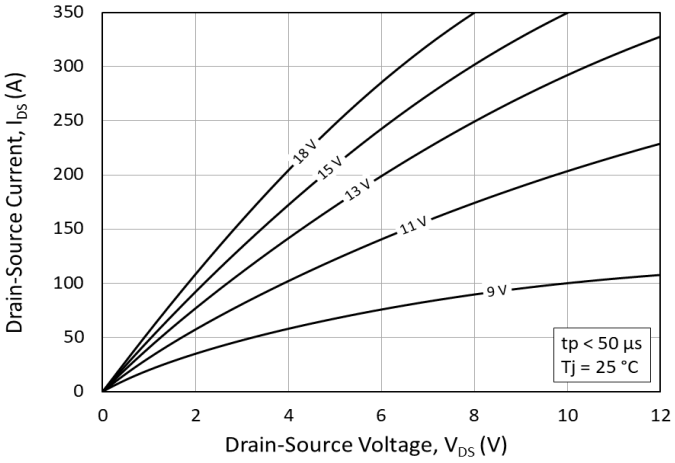

Figure 2. Output Characteristics T_{VJ} = 25 °C

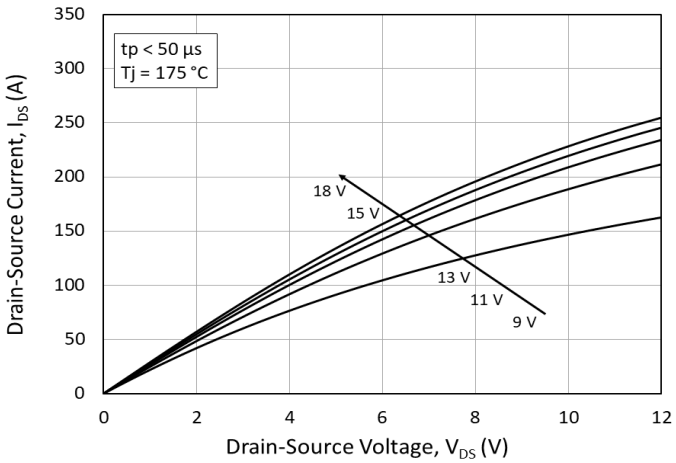

Figure 3. Output Characteristics T_{VJ} = 175 °C

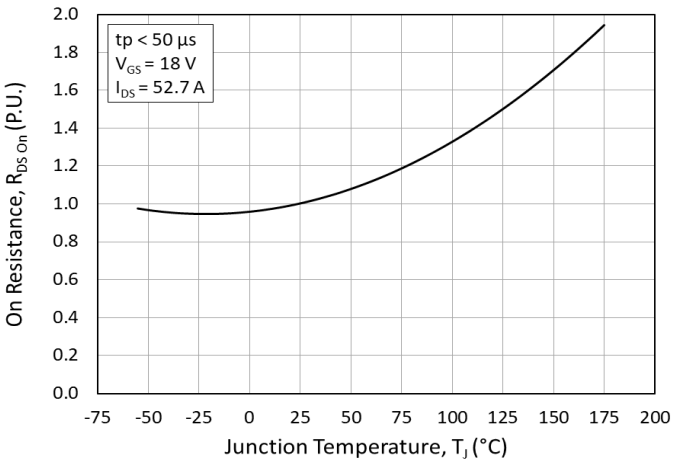

Figure 4. Normalized On-Resistance vs. Temperature

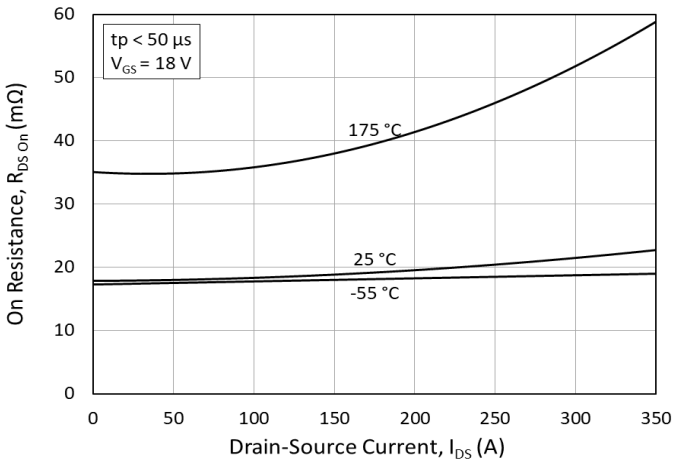

Figure 5. On-Resistance vs. Drain Current for Various Temperatures

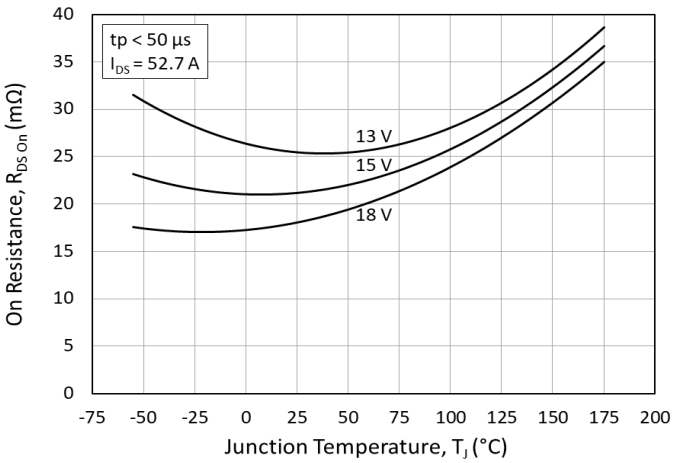

Figure 6. On-Resistance vs. Temperature for Various Gate Voltages

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Typical Performance

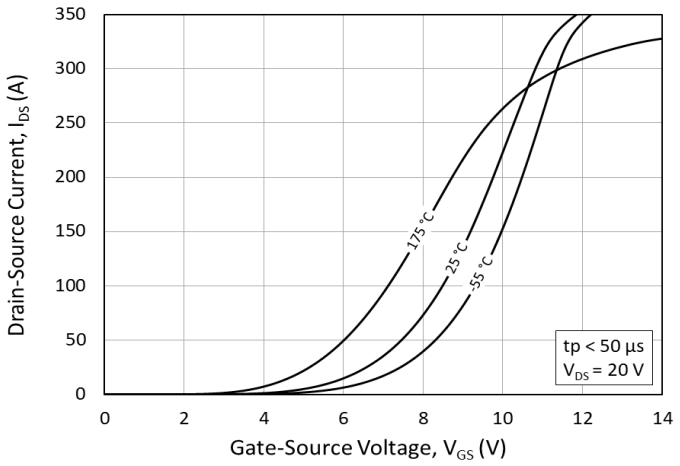

Figure 7. Transfer Characteristic for Various Junction Temperatures

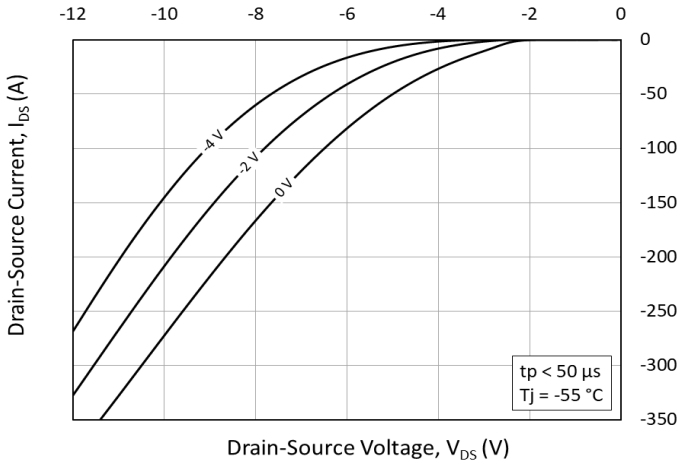

Figure 8. Body Diode Characteristic at T_{VJ} = -55 °C

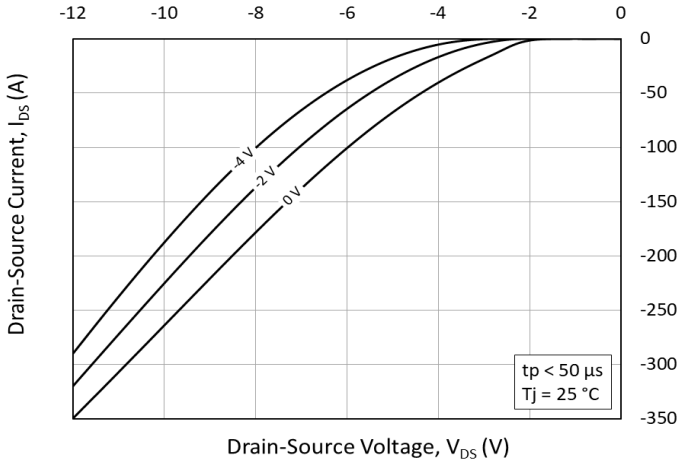

Figure 9. Body Diode Characteristic at T_{VJ} = 25 °C

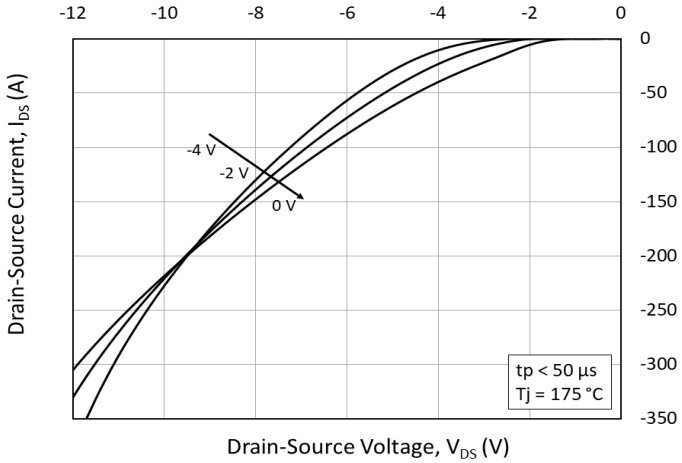

Figure 10. Body Diode Characteristic at T_{VJ} = 175 °C

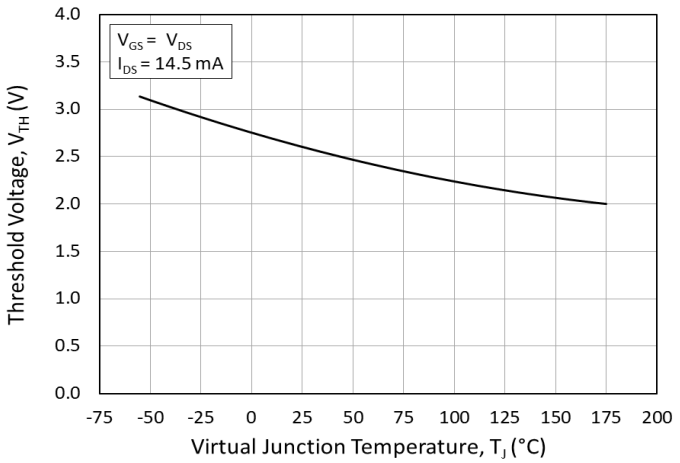

Figure 11. Threshold Voltage vs. Temperature

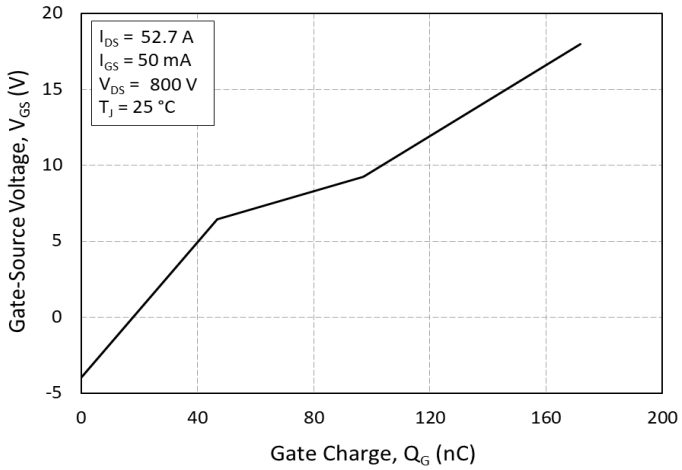

Figure 12. Gate Charge Characteristics

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Typical Performance

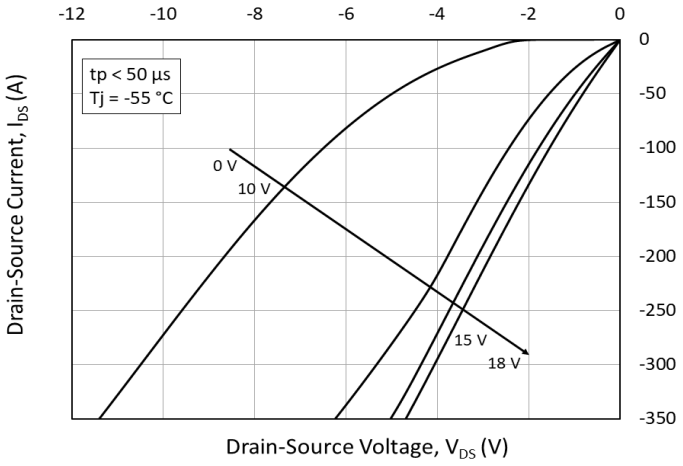

Figure 13. 3rd Quadrant Characteristic at T_{VJ} = -55 °C

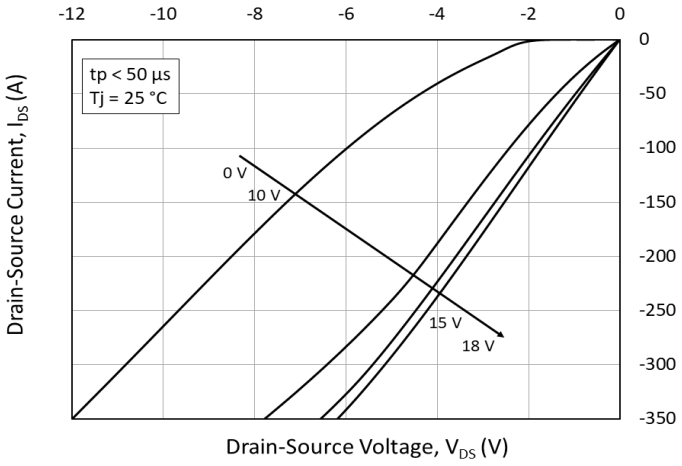

Figure 14. 3rd Quadrant Characteristic at T_{VJ} = 25 °C

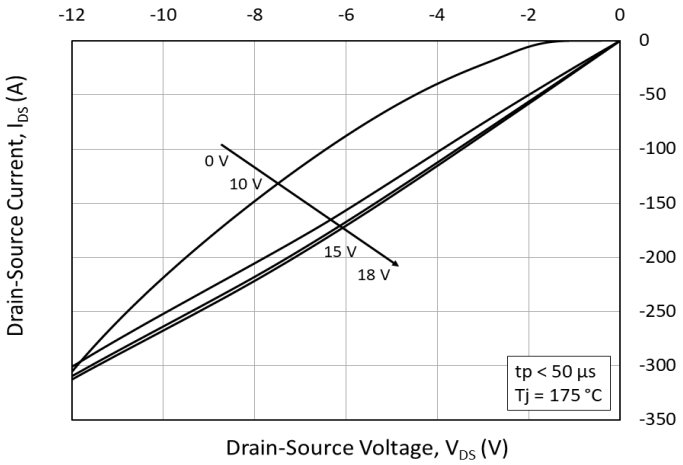

Figure 15. 3rd Quadrant Characteristic at T_{VJ} = 175 °C

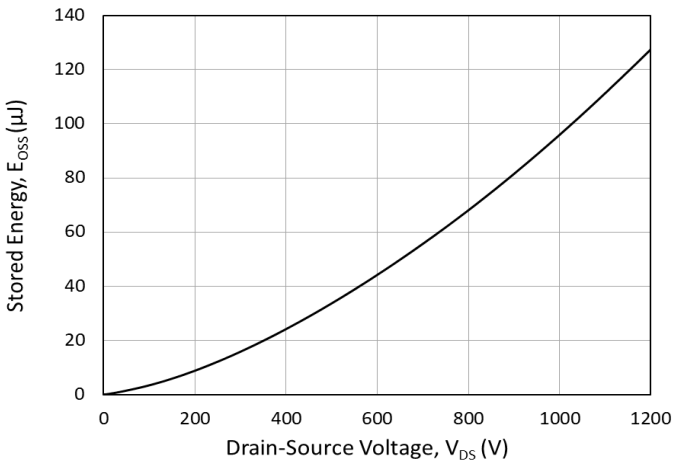

Figure 16. Output Capacitor Stored Energy

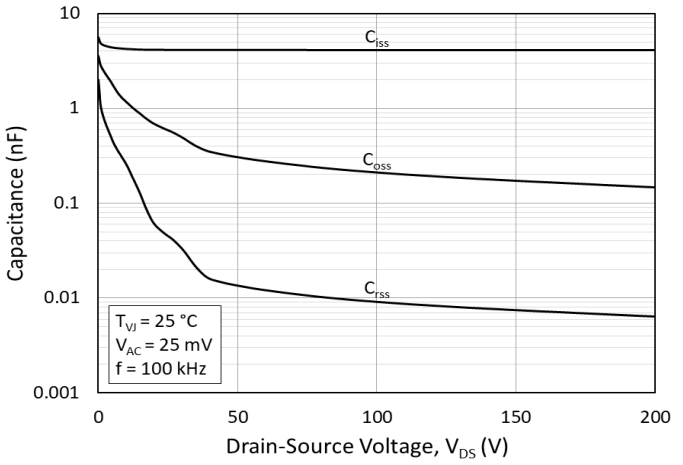

Figure 17. Capacitances vs. Drain-Source Voltage (0-200 V)

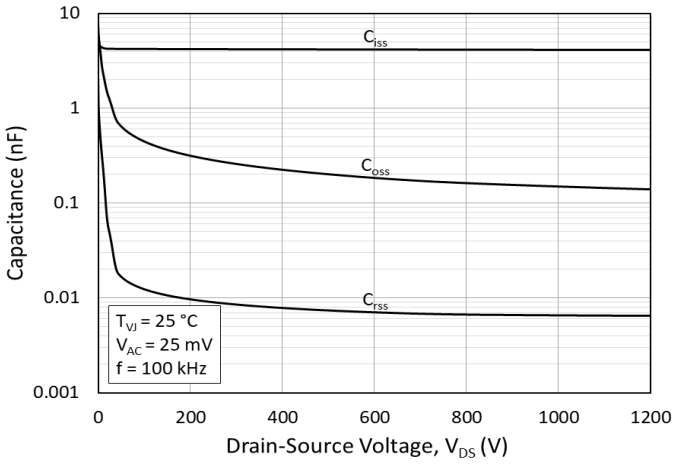

Figure 18. Capacitances vs. Drain-Source Voltage (0-1200 V)

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Typical Performance

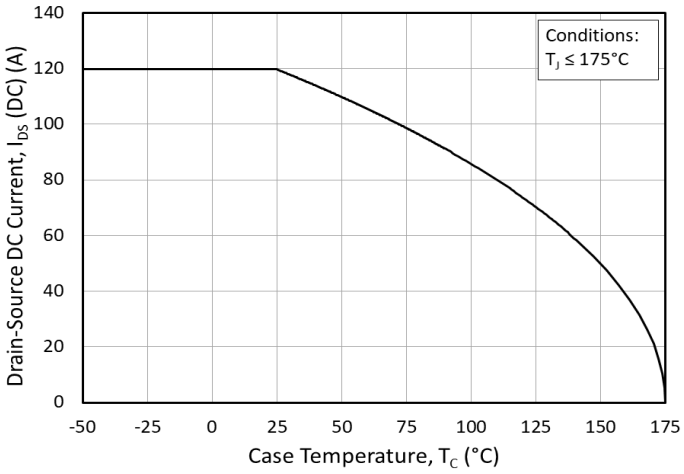

Figure 19. Continuous Drain Current Derating vs. Case Temperature

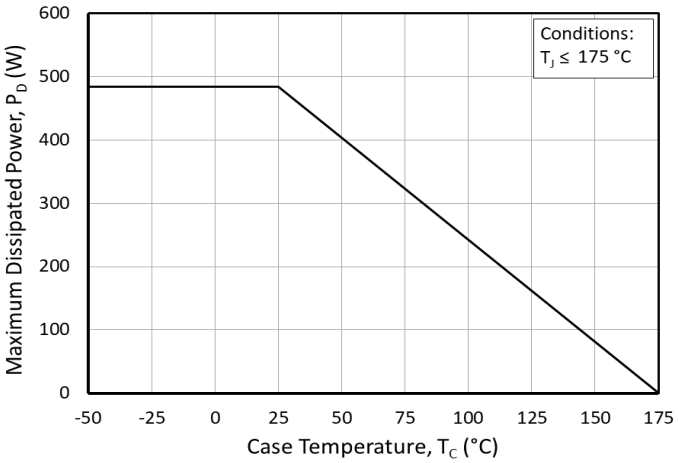

Figure 20. Maximum Power Dissipation Derating vs. Case Temperature

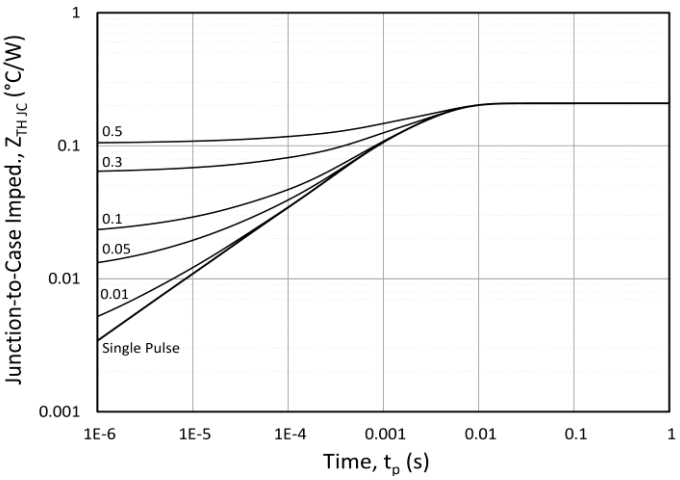

Figure 21. Transient Thermal Impedance (Junction - Case) °C

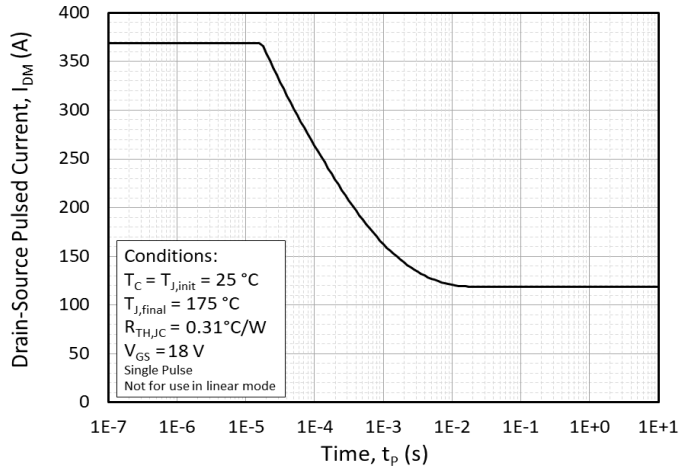

Figure 22. Safe Operating Area

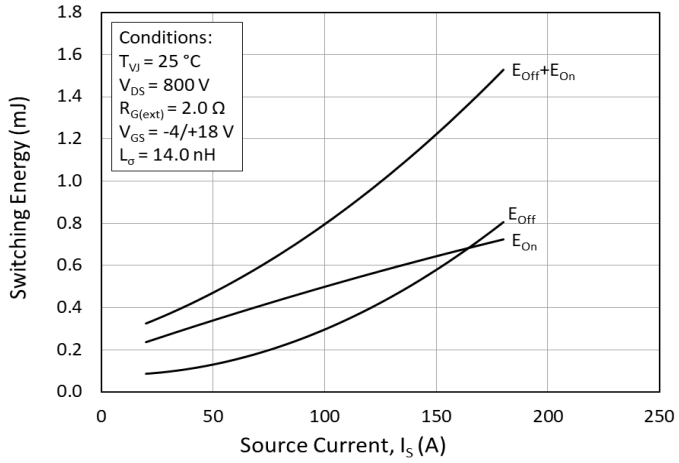

Figure 23. Clamped Inductive Switching Energy vs. Drain Current (V_{DD} = 800 V)

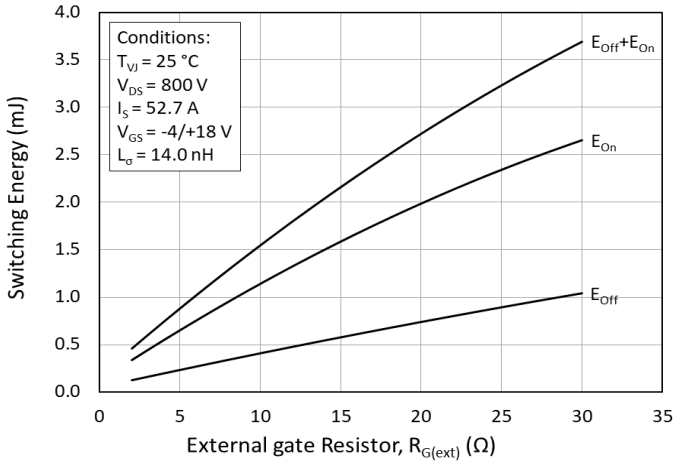

Figure 24. Clamped Inductive Switching Energy vs. $R_{G(ext)}$

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Typical Performance

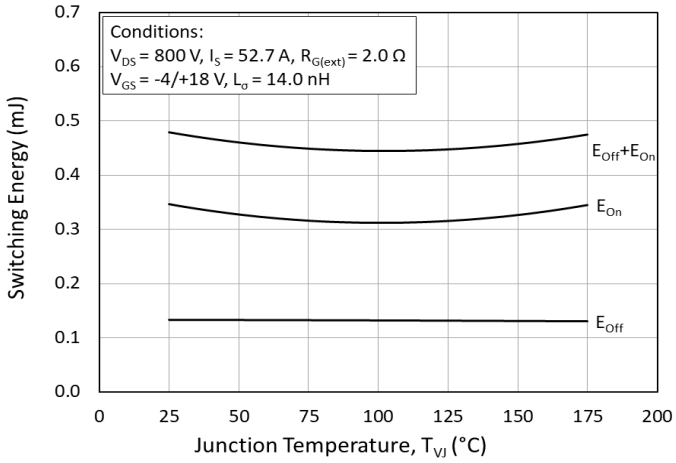

Figure 25. Clamped Inductive Switching Energy vs. Temperature

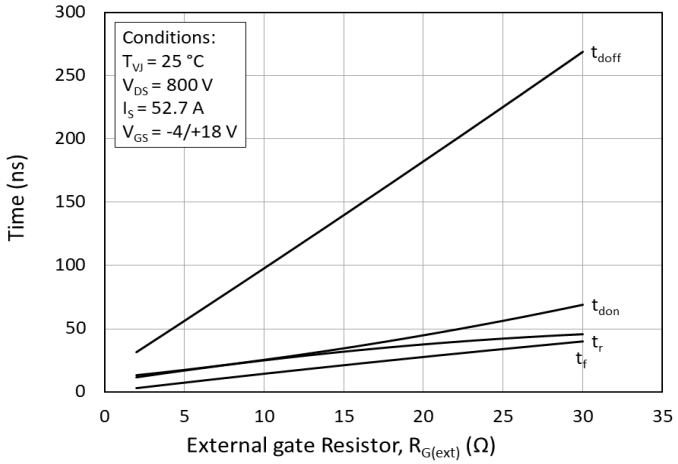

Figure 26. Switching Times vs. $R_{G(ext)}$

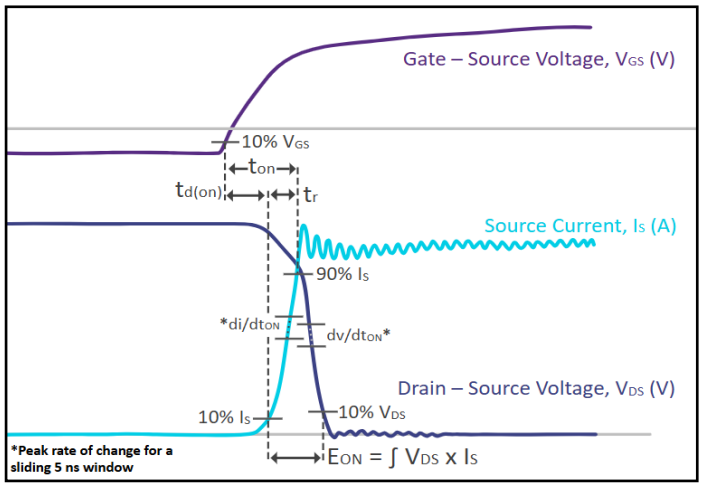

Figure 27. Turn On Switching Time Definition

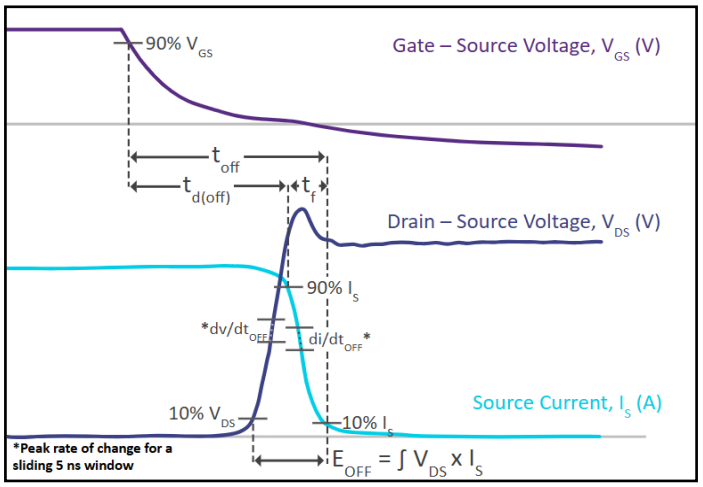

Figure 28. Turn Off Switching Time Definition

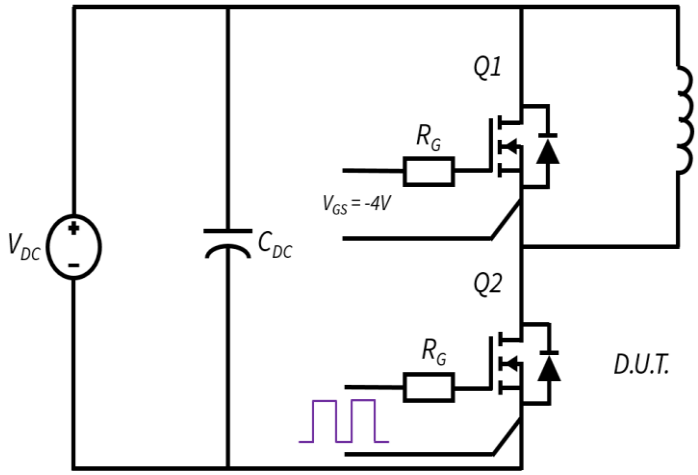

Figure 29. Clamped Inductive MOSFET Switching Waveform Test Circuit

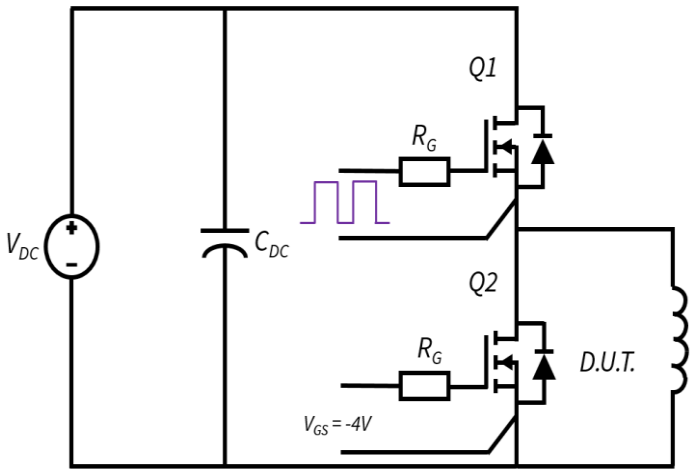

Figure 30. Clamped Inductive Body Diode Switching Waveform Test Circuit

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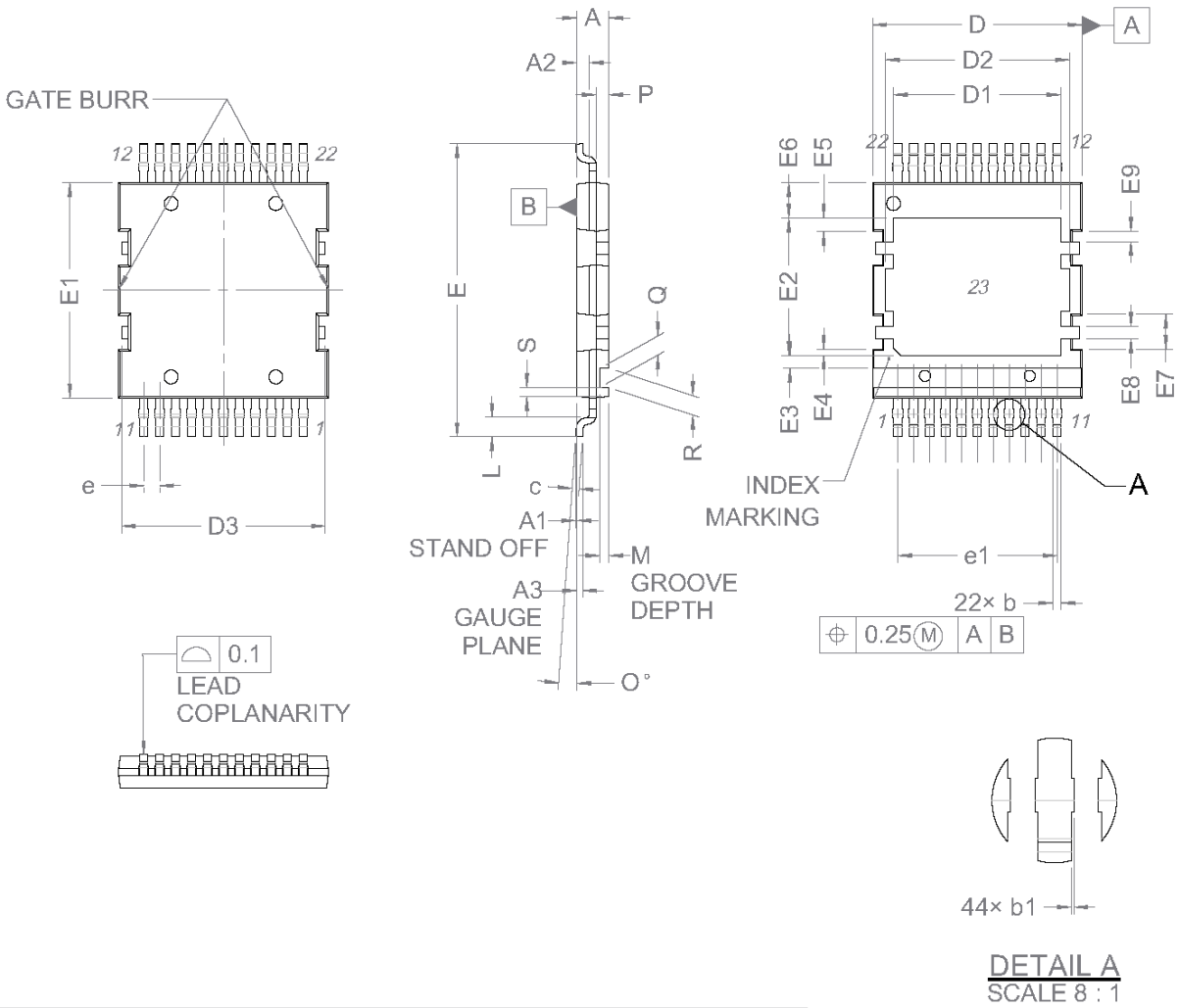
Package Dimensions



SYMBOL	MIN	MAX	SYMBOL	MIN	MAX
A	2.2	2.35	E6	2.53	
A1	0	0.15	E7	2.4	
A2	0.9		E8	0.9	
A3	0.5		E9	0.75	
b	0.5	0.7	e	1.14	
b1	-	0.15	e1	11.4	
c	0.46	0.58	L	1.3	
D	14.9	15.1	M	0.6	
D1	12		N	22	
D2	13.2		O	0°	8°
D3	14.5	14.7	P	0.9	
E	20.81	21.11	P1	0.7	0.9
E1	15.3	15.5	P2	0.9	1.1
E2	9.83		Q	1.6	
E3	0.625		R	1.7	
E4	0.45		S	0.631	
E5	0.95				

PIN	DESCRIPTION
1	GATE
2	KELVIN
3-11	SOURCE
12-23	DRAIN

NOTE:
1. ALL METAL SURFACES ARE TIN PLATED (MATTE), EXCEPT AREA OF CUT
2. ALL DIMENSIONS ARE LISTED IN MILLIMETERS. ANGLES IN DEGREES
3. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
4. DIMENSIONS DO NOT INCLUDE MOLD FLASH (0.15mm MAX PER SIDE) OR GATE BURR (0.3mm MAX)
5. THE LEAD SIDE IS COMPREHENSIVE OF THE THICKNESS OF THE LEAD FINISH MATERIAL

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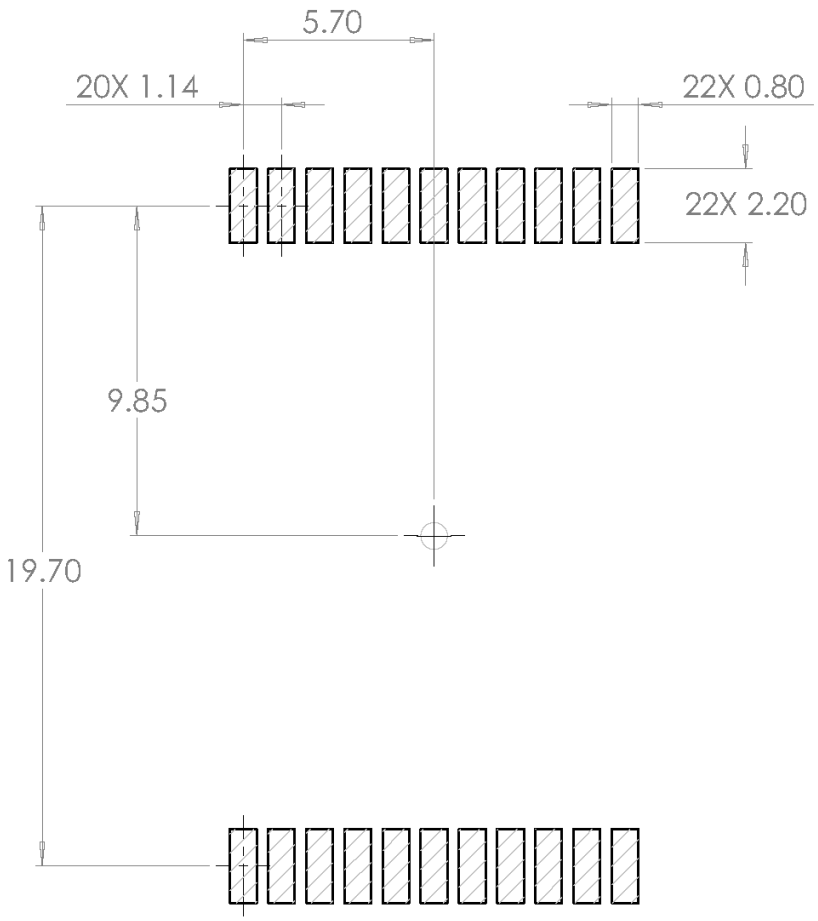
Recommended Solder Pad Layout

All dimensions in mm



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Revision History

Documents Version	Date of Change	Description of Changes
1	6/10/2026	Initial Release

Appendix

Appendix Number	Description
A1	The following are recommendations for turning off the MOSFET with 0 V: • Measure the V_{GS} spike accurately using high-CMRR probes and low common mode noise measurements. • For the safe operation of the device, the voltage spike shall remain < 5 V for a time duration of < 40 ns.

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